

IGBT MODULE (N series)

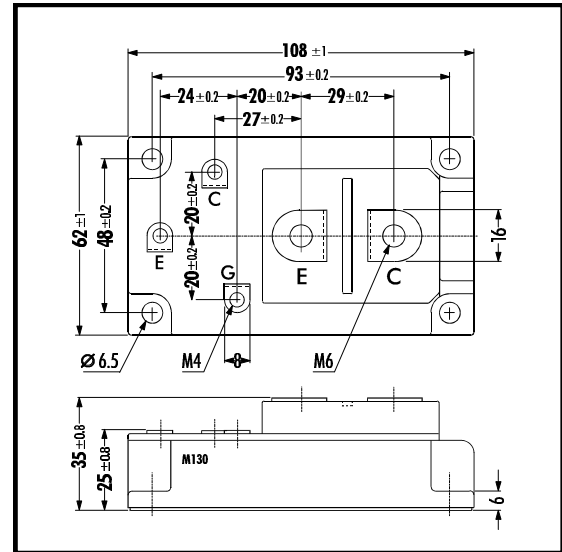
■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Improved FWD Characteristic
- Minimized Internal Stray Inductance
- Overcurrent Limiting Function (4-5 Times Rated Current)

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

■ Outline Drawing



■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	1200	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	Continuous	I _C	400
	1ms	I _{C PULSE}	800
	Continuous	-I _C	400
	1ms	-I _{C PULSE}	800
Max. Power Dissipation	P _C	3100	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
Isolation Voltage	V _{is}	2500	V
Screw Torque	Mounting *1	3.5	Nm
	Terminals *2	4.5	
	Terminals *3	1.7	

Note: *1:Recommendable Value; 2.5 ~ 3.5 Nm (M5) or (M6)
 *2:Recommendable Value; 3.5 ~ 4.5 Nm (M6)
 *3:Recommendable Value; 1.3 ~ 1.7 Nm (M4)

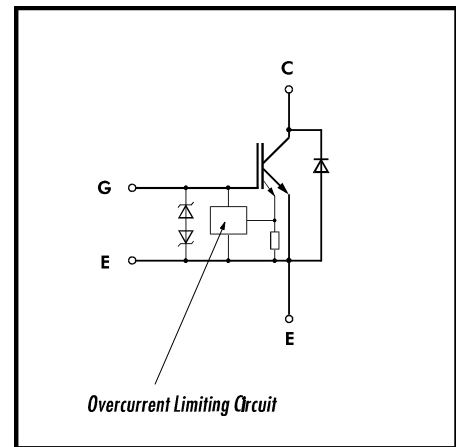
• Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CEs}	V _{GE} =0V V _{CE} =1200V			4.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			60	µA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =400mA	4.5		7.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =400A			3.3	V
Input capacitance	C _{ies}	V _{GE} =0V		64000		pF
Output capacitance	C _{oes}	V _{CE} =10V		23200		
Reverse Transfer capacitance	C _{res}	f=1MHz		20640		
Turn-on Time	t _{ON}	V _{CC} =600V		0.75	1.2	µs
	t _r	I _C =400A		0.25	0.6	
Turn-off Time	t _{OFF}	V _{GE} =± 15V		1.05	1.5	
	t _f	R _G =1.8Ω		0.35	0.5	
Diode Forward On-Voltage	V _F	I _F =400A V _{GE} =0V			3.0	V
Reverse Recovery Time	t _{rr}	I _F =400A			350	ns

• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(I-C)}	IGBT			0.04	°C/W
	R _{th(I-c)}	Diode			0.12	
	R _{th(c-f)}	With Thermal Compound		0.0125		

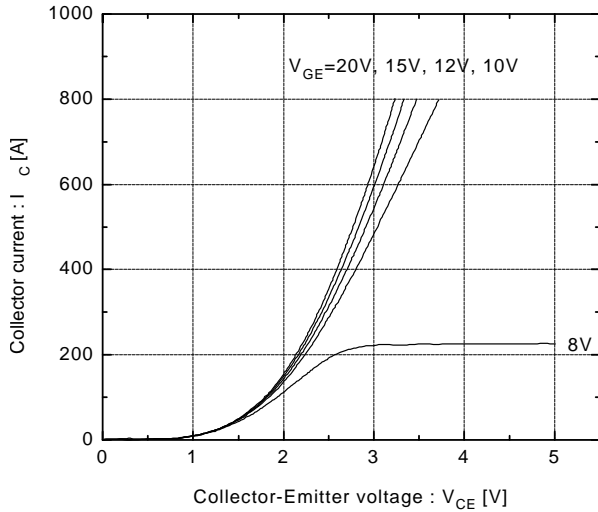
■ Equivalent Circuit



Overcurrent Limiting Circuit

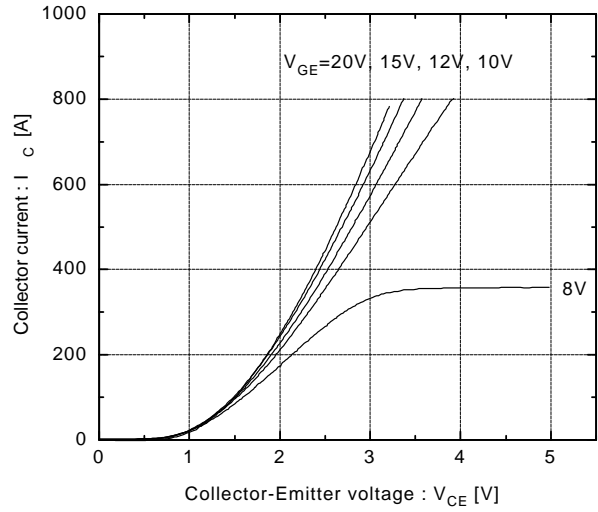
Collector current vs. Collector-Emitter voltage

$T_J=25^\circ\text{C}$



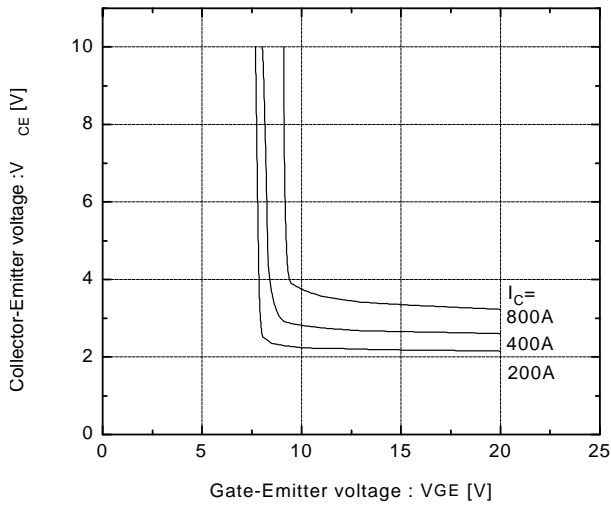
Collector current vs. Collector-Emitter voltage

$T_J=125^\circ\text{C}$



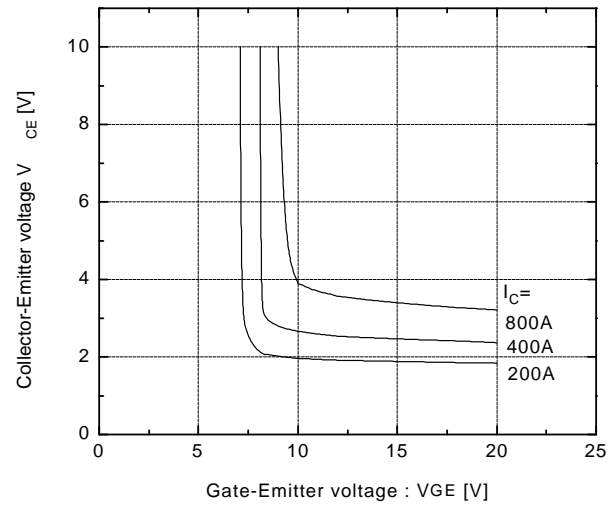
Collector-Emitter vs. Gate-Emitter voltage

$T_J=25^\circ\text{C}$



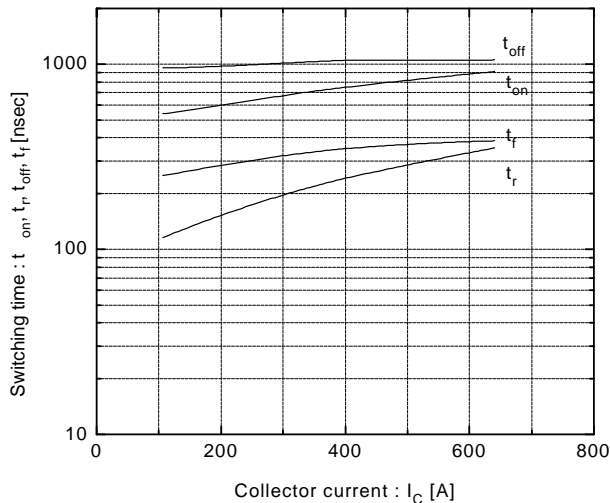
Collector-Emitter vs. Gate-Emitter voltage

$T_J=125^\circ\text{C}$



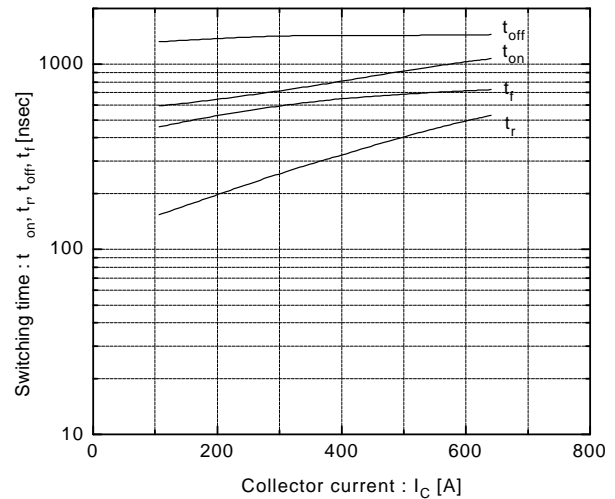
Switching time vs. Collector current

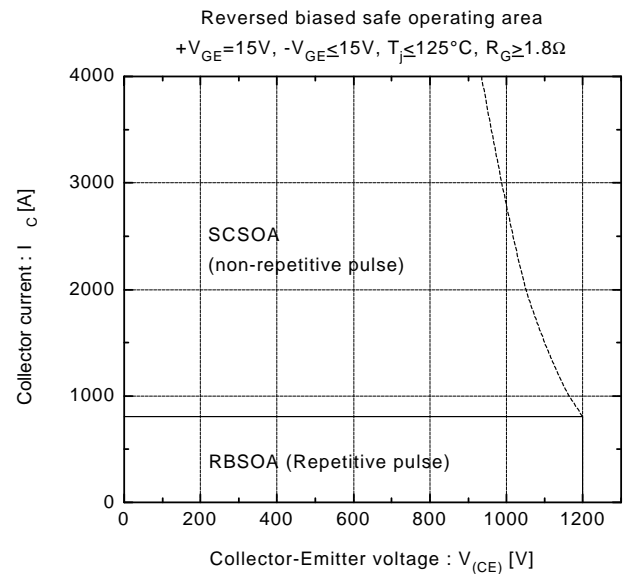
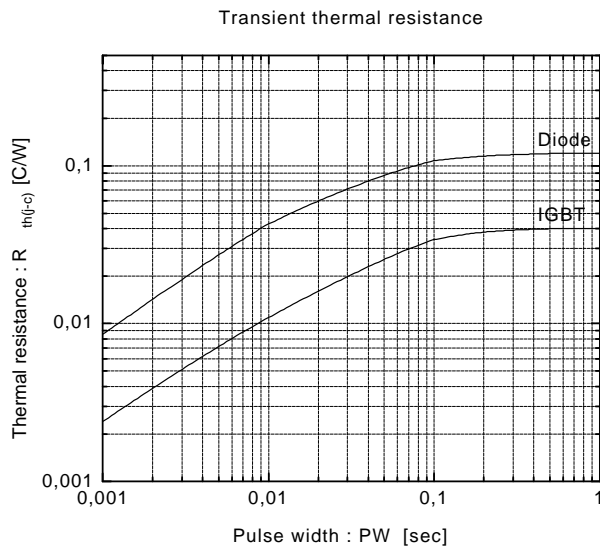
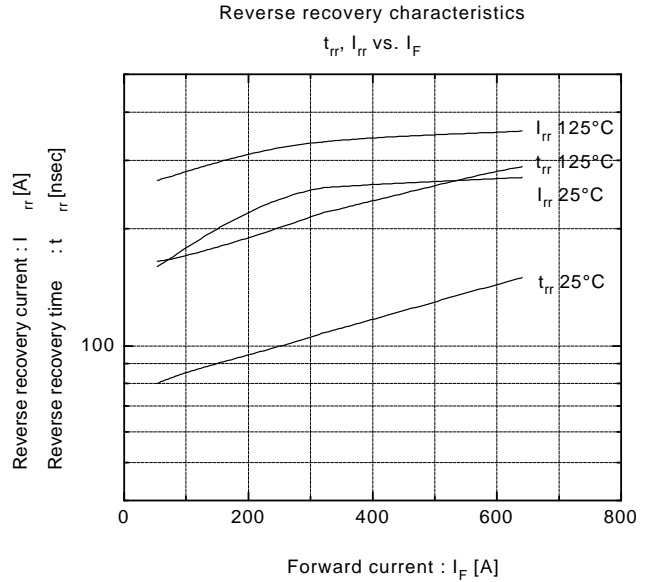
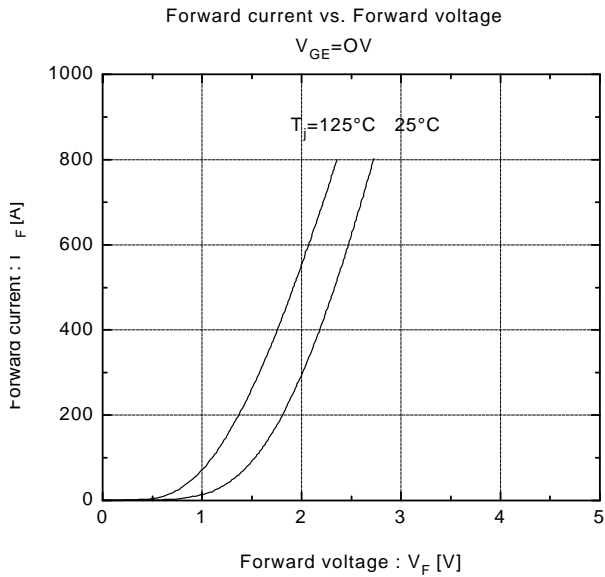
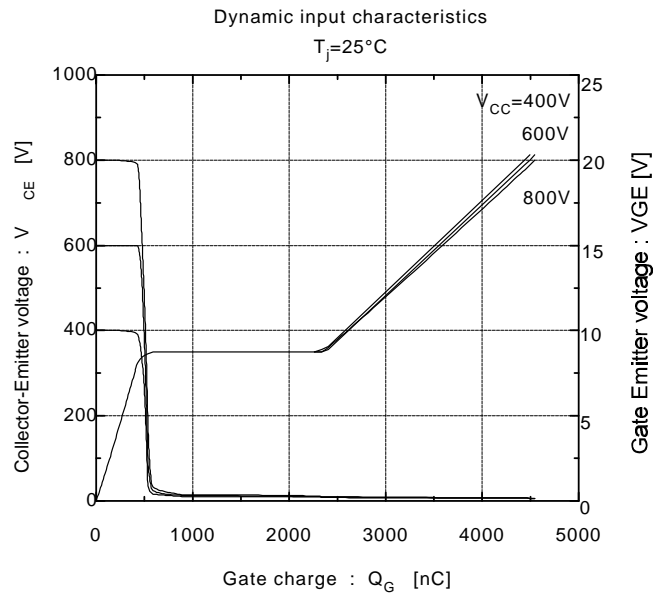
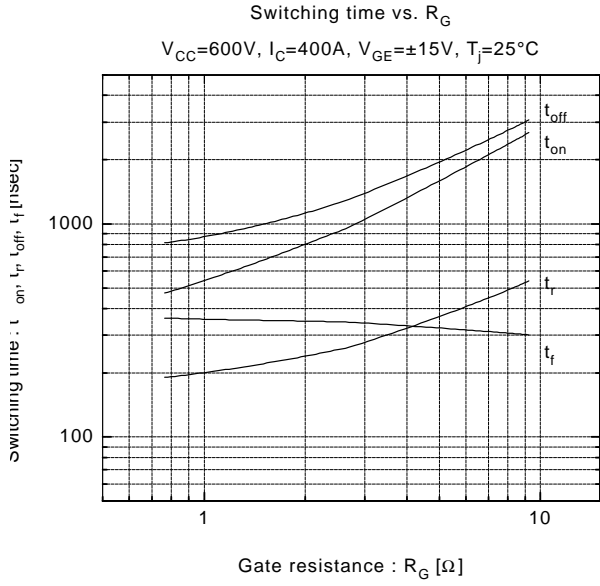
$V_{CC}=600\text{V}, R_G=1.8\Omega, V_{GE}=\pm 15\text{V}, T_J=25^\circ\text{C}$



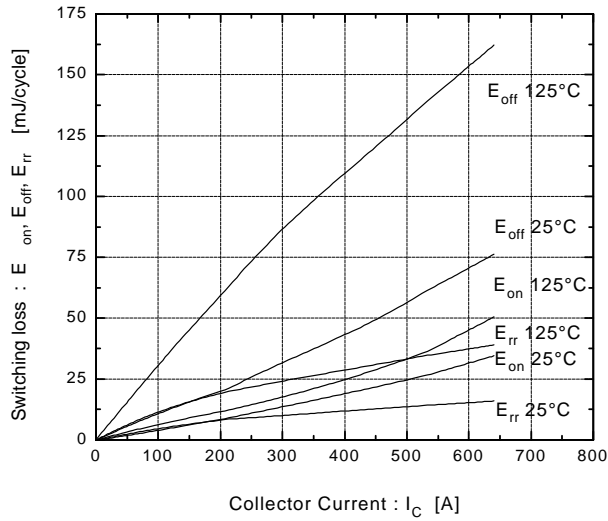
Switching time vs. Collector current

$V_{CC}=600\text{V}, R_G=1.8\Omega, V_{GE}=\pm 15\text{V}, T_J=125^\circ\text{C}$

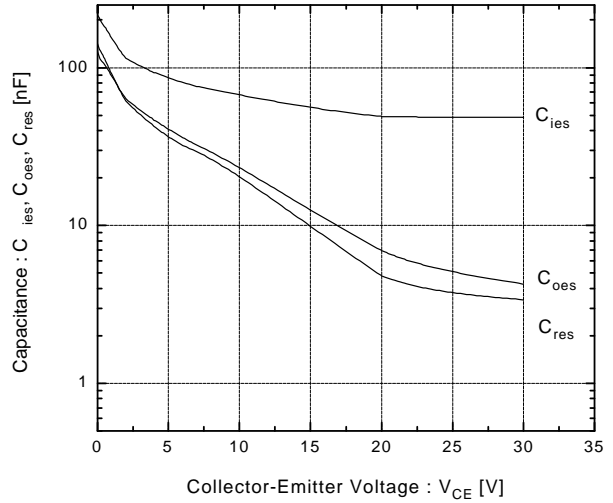




Switching loss vs. Collector current
 $V_{CC}=600V, R_G=1.8\Omega, V_{GE}=\pm 15V$



Capacitance vs. Collector-Emitter voltage
 $T_J=25^\circ C$



Fuji Electric GmbH

Lyoner Straße 26

D-60528 Frankfurt/M

Tel.: 069 - 66 90 29 - 0
 Fax.: 069 - 66 90 29 - 56

Fuji Electric (UK) Ltd.

Commonwealth House
 2 Chalkhill Road Hammersmith

London W6 8DW, UK

Tel.: 0181 - 233 11 30
 Fax.: 0181 - 233 11 60